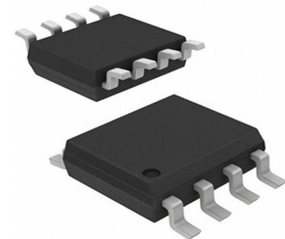


Description

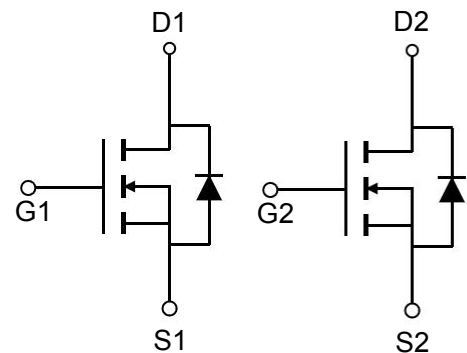
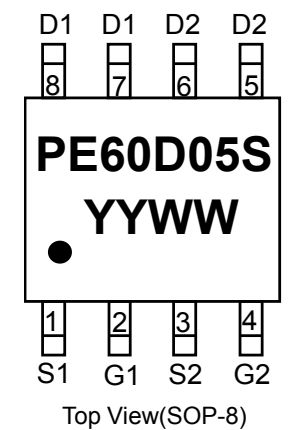
The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary

$V_{DS}(V)$	$R_{DS(on)}(m\Omega)$	$I_D(A)$
60	32@ $V_{GS}=4.5V$	5



SOP-8L



Internal Structure

Absolute maximum rating@25°C

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	V_{DS}	60	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	5	A
Drain Current-Continuous ($T_C=100^{\circ}C$)	$I_D (100^{\circ}C)$	3.5	A
Pulsed Drain Current	I_{DM}	24	A
Maximum Power Dissipation	P_D	2	W
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 to 150	$^{\circ}C$
Thermal Characteristics			
Parameter	Symbol	Maximum	Units
Thermal Resistance,Junction-to-Ambient(Note 1)	$R_{\theta JA}$	62.5	$^{\circ}C/W$

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	I _D =250μA, V _{GS} =0V	60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V	-	-	±100	μA
On Characteristics (Note 2)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.2	1.6	2.5	V
Static Drain-Source On-Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =5A	-	26	35	mΩ
		V _{GS} =4.5V, I _D =5A	-	32	45	
Forward Transconductance	g _{FS}	V _{DS} =5V, I _D =5A	11	-	-	S
Dynamic Characteristics (Note 3)						
Input Capacitance	C _{ISS}	V _{GS} =0V, V _{DS} =30V, f=1MHz	-	979	-	pF
Output Capacitance	C _{OSS}		-	120	-	pF
Reverse Transfer Capacitance	C _{RSS}		-	100	-	pF
Switching Characteristics (Note 3)						
Total Gate Charge	Q _g	V _{GS} =10V, V _{DS} =30V, I _D =5A	-	22		nC
Gate-Source Charge	Q _{gs}		-	3.3	-	
Gate-Drain Charge	Q _{gd}		-	5.2	-	
Turn-On Delay Time	t _{d(on)}	V _{DD} =30V, R _{GEN} =3Ω, V _{GS} =10V, R _L =6.7Ω	-	5.2	-	ns
Turn-Off Delay Time	t _{d(off)}		-	3	-	ns
Turn-On Rise Time	t _r		-	17	-	ns
Turn-On Fall Time	t _f		-	2.5	-	ns
Drain-Source Diode Characteristics						
Drain Forward Voltage(Note 2)	V _{SD}	V _{GS} =0V, I _S =5A	-	-	1.2	V
Drain Forward Current(Note 1)	I _S		-	-	5	A
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible(turn-on is dominated by LS+LD)				

Notes:

- 1.Surface Mounted on FR4 Board, $t \leq 10$ sec.
- 2.Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
- 3.Guaranteed by design, not subject to production

Typical Characteristics

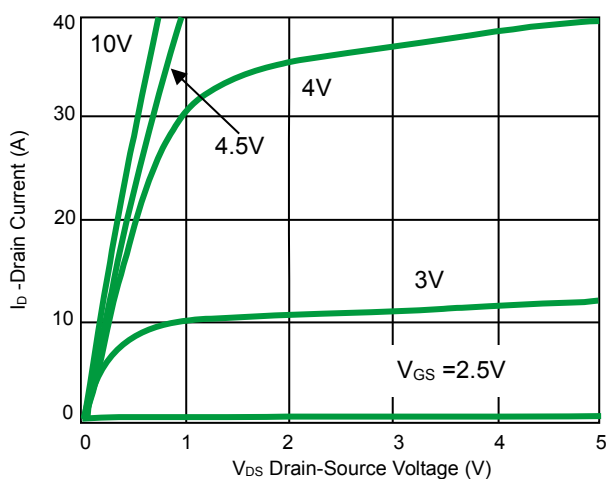


Fig 1. Output Characteristics

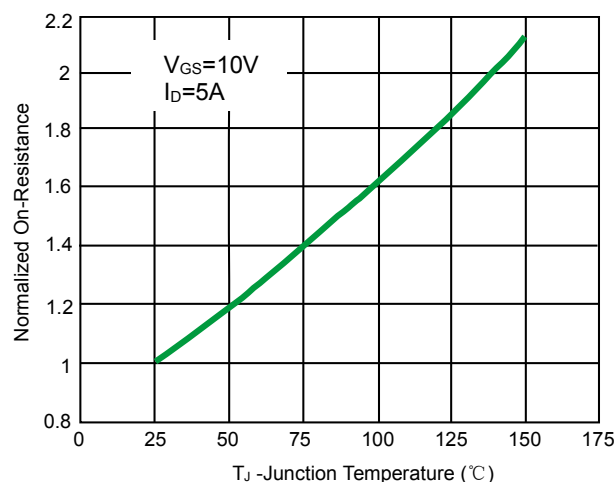
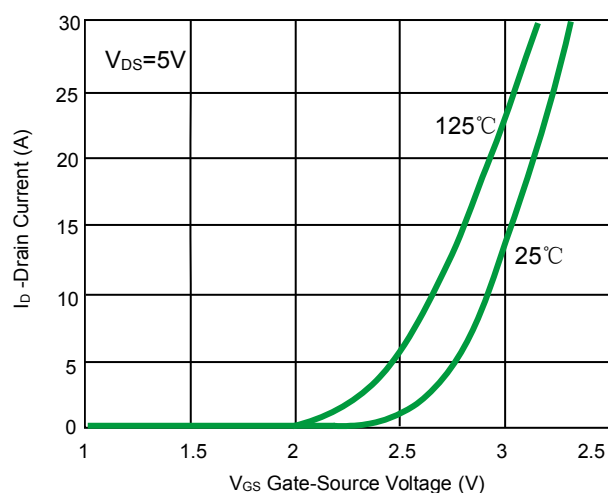
Fig 2. $R_{DS(on)}$ -Junction Temperature($^{\circ}C$)

Fig 3. Transfer Characteristics

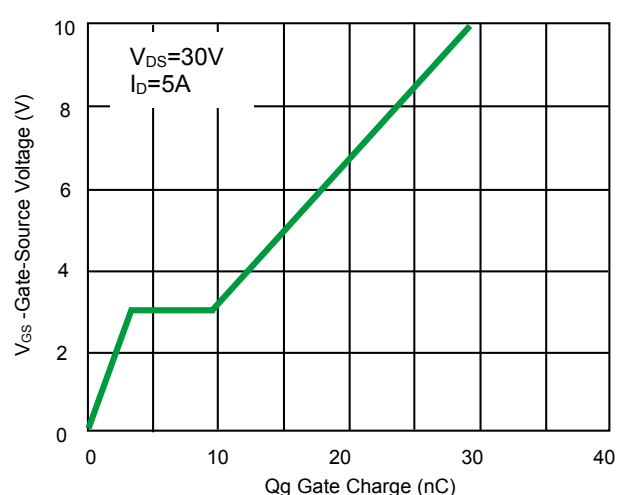


Fig 4. Gate Charge

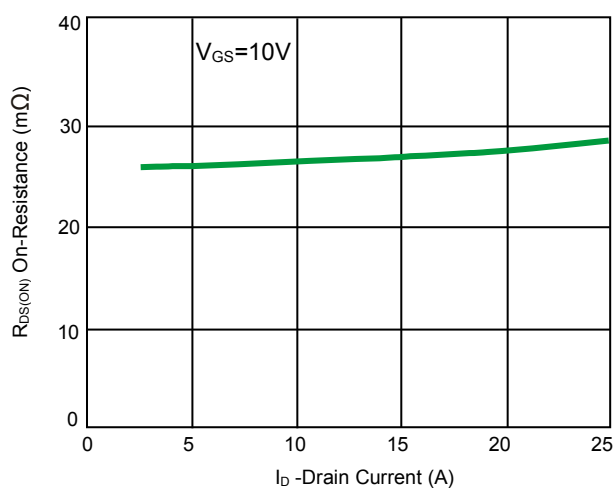
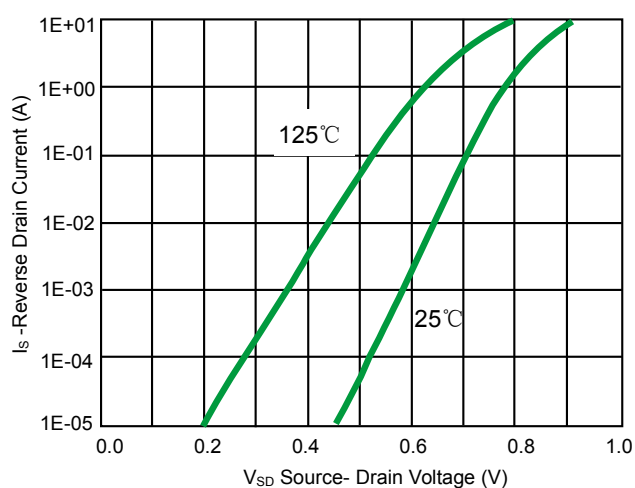
Fig 5. $R_{DS(on)}$ -Drain Current

Fig 6. Source-Drain Diode Forward

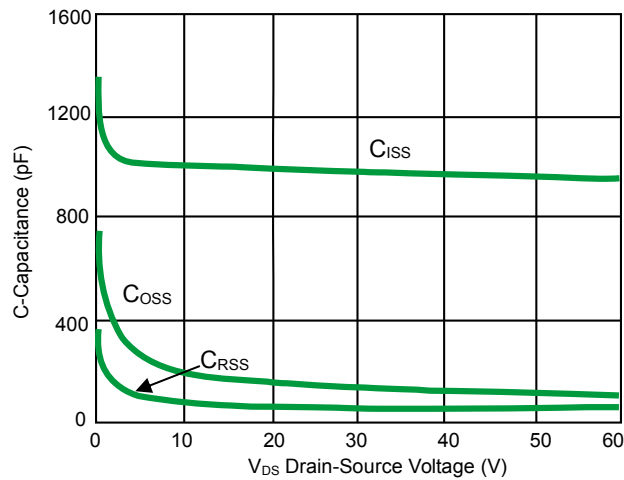
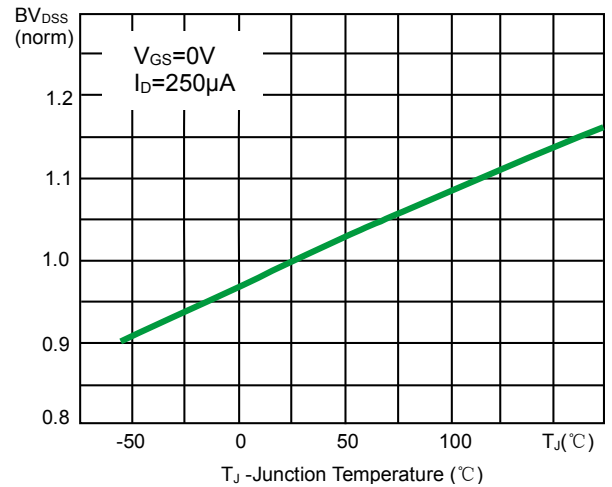
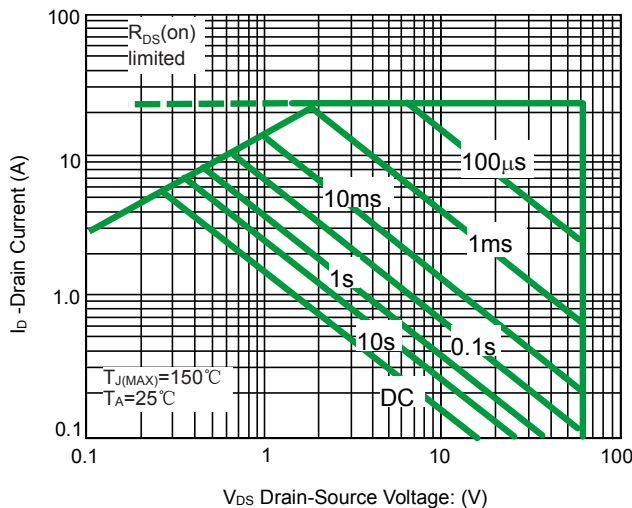
Fig 7. Capacitance vs. V_{DS} Fig 8. BV_{DSS} vs. Junction Temperature

Figure 9. Safe Operation Area

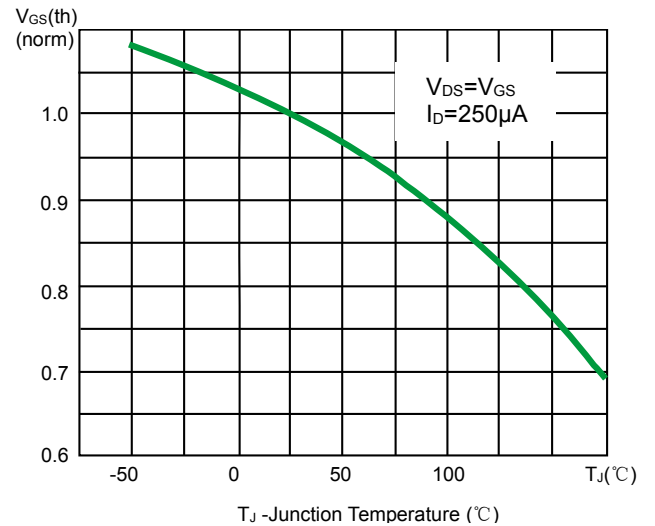
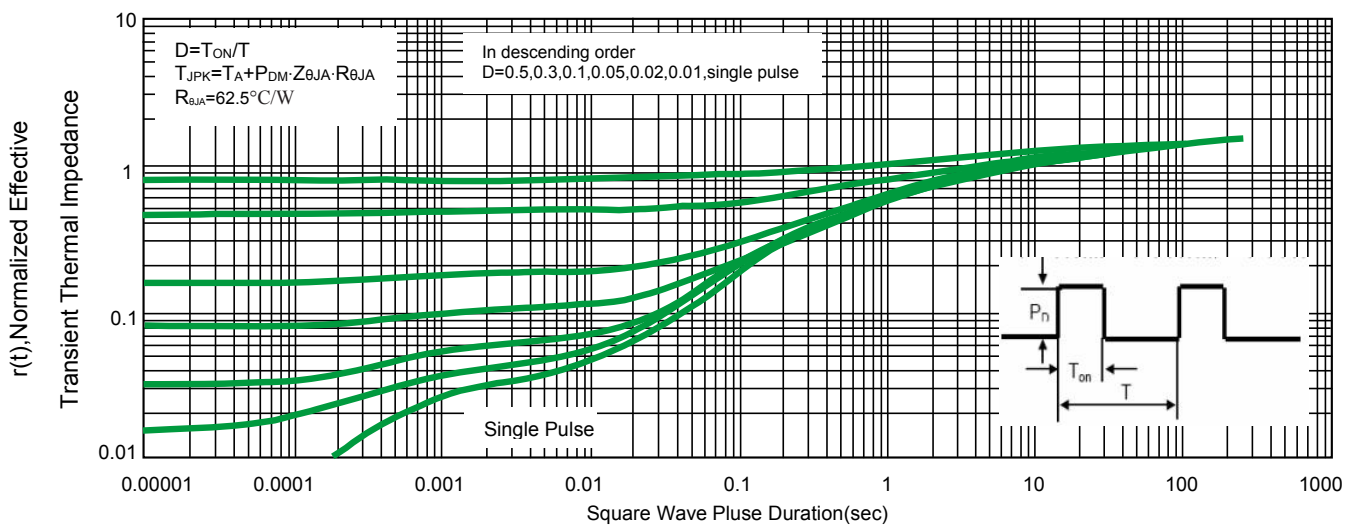
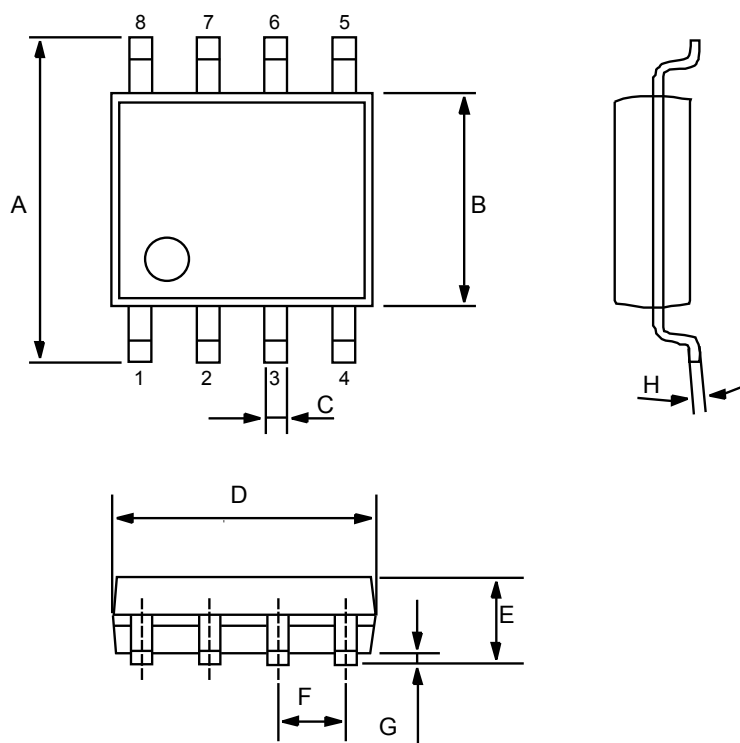
Figure 10. $V_{GS(th)}$ VS Junction Temperature

Figure 11. Normalized Maximum Transient Thermal Impedance

Product dimension(SOP-8)

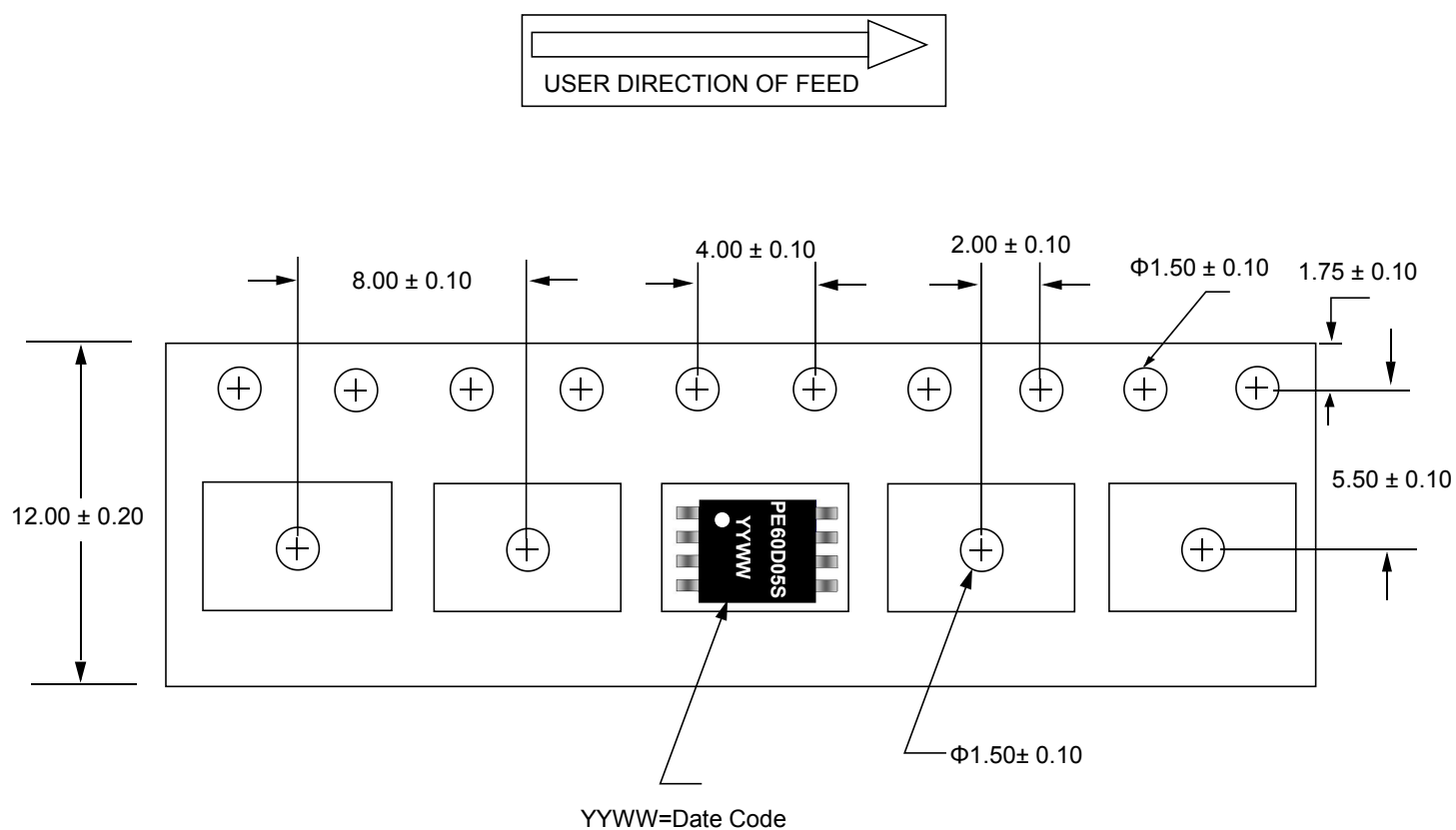


Dim	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	5.800	6.200	0.228	0.244
B	3.800	4.000	0.150	0.157
C	0.330	0.510	0.013	0.020
D	4.700	5.100	0.185	0.200
E	1.350	1.750	0.053	0.069
F	1.270 (BSC)		0.050 (BSC)	
G	0.100	0.250	0.004	0.010
H	0.170	0.250	0.006	0.010

Ordering information

Device	Package	Reel	Shipping
PDNM8P60V5	SOP-8 (Pb-Free)	13"	2500 / Tape & Reel

Load with information



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